

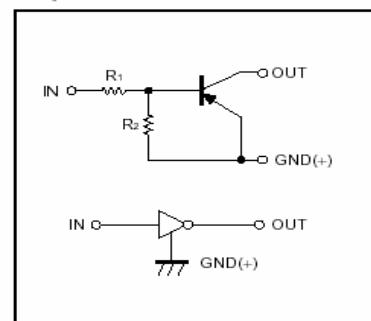
DIGITAL TRANSISTOR(PNP)

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Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

●Equivalent circuit



PIN CONNECTIONS AND MARKING

<p>DTA123YE</p> <p>1.IN 2.GND 3.OUT</p> <p>SOT-523 Addreviated symbol: 52</p>	<p>DTA123YUA</p> <p>1.IN 2.GND 3.OUT</p> <p>SOT-323 Addreviated symbol: 52</p>
<p>DTA123YKA</p> <p>1.IN 2.GND 3.OUT</p> <p>SOT-23-3L Addreviated symbol: 52</p>	<p>DTA123YCA</p> <p>1.IN 2.GND 3.OUT</p> <p>SOT-23 Addreviated symbol: 52</p>
<p>DTA123YSA</p> <p>1.GND 2.OUT 3.IN</p> <p>TO-92S (1) (2) (3)</p>	

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTA123Y□)					Unit
		E	UA	KA	CA	SA	
Supply voltage	V _{CC}			-50			V
Input voltage	V _{IN}			-12~5			V
Output current	I _O			-100			mA
	I _{C(MAX)}			-100			
Power dissipation	P _d	150		200		300	mW
Junction temperature	T _j			150			°C
Storage temperature	T _{stg}			-55~150			°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			-0.3	V	V _{CC} =-5V , I _O =-100μA
	V _{I(on)}	-3				V _O =-0.3V , I _O =-20 mA
Output voltage	V _{O(on)}			-0.3	V	I _O /I _I =-10mA/-0.5mA
Input current	I _I			-3.8	mA	V _I =-5V
Output current	I _{O(off)}			-0.5	μA	V _{CC} =-50V , V _I =0
DC current gain	G _I	33				V _O =-5V , I _O =-10mA
Input resistance	R _I	1.54	2.2	2.86	KΩ	
Resistance ratio	R ₂ /R ₁	3.6	4.5	5.5		
Transition frequency	f _T		250		MHz	V _{CE} =-10V , I _E =5mA,f=100MHz

Typical Characteristics

●Electrical characteristic curves
